## NSN 5962-01-334-3898

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View Online at https://aerobasegroup.com/nsn/5962-01-334-3898 **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.02 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and burn in and monolithic and programmable and schottky **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 13 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder

**Voltage Rating And Type Per Characteristic:** 

7.0 volts power source

**Memory Device Type:** 

Rom

**Test Data Document:** 

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

24 printed circuit

**Specification Data:** 

81349-mil-m-38510/210 government specification

Shelf Life:

N/a

**Unit Of Measure:** 

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**Demilitarization:** 

Yes - demil/mli

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